



SOT-23 Formed SMD Package

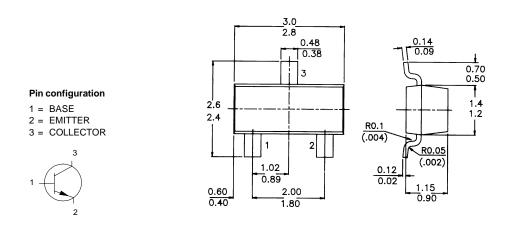
CMBT4124

# GENERAL PURPOSE TRANSISTOR

N-P-N transistor

*Marking CMBT4124 = 5C* 

## PACKAGE OUTLINE DETAILS ALL DIMENSIONS IN mm



#### ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)	$-V_{CBO}$	max.	30	V
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	25	V
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	5	V
Collector current (d.c.)	$-I_C$	max.	200	mА
Total power dissipation at $T_{amb} = 25^{\circ}C$	P <sub>tot</sub>	max	225	mW
D.C. current gain				
$-I_C = 2 mA; -V_{CF} = 1 V$	h	min.	120	
-iC - z mA, -vCE - i v	h <sub>FE</sub>	max.	360	

<b>RATINGS</b> (at $T_A = 25^{\circ}C$ unless otherwise specified)				
Limiting values				
Collector-base voltage (open emitter)	$-V_{CBO}$	max.	30	V
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	25	V
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	5	V
Collector current (d.c.)	$-I_C$	max.	200	mА
Total power dissipation at $T_{amb} = 25^{\circ}C$	P <sub>tot</sub>	max	225	mW
Storage temperature	T <sub>stg</sub>	-55 to	+150	° C
Junction temperature	Тj	max.	150	° C

### CMBT4124

#### THERMAL CHARACTERISTICS

$T_i = P (R_{th i-t} + R_{th s-a}) + T_{amb}$									
Thermal resistance									
from junction to ambient	R <sub>th j-a</sub>		556	°C/mW					
<b>CHARACTERISTICS</b> (at $T_A = 25^{\circ}C$ unless otherwise specified)									
Collector-emitter breakdown voltage									
$-I_C = 1 mA; I_B = 0$	-V <sub>(BR)CEO</sub> min.		25	V					
Collector-base breakdown voltage	. ,								
$-I_C = 10 \text{ mA}; I_E = 0$	-V <sub>(BR)CBO</sub> min.		30	V					
Emitter-base breakdown voltage		()							
$-I_E = 10 \text{ mA}; I_C = 0$	-V <sub>(BR)EBO</sub> min.		5	V					
Collector cut-off current									
$-V_{CB} = 20 V; I_E = 0 V$	-I <sub>CBO</sub>	max.	50	nA					
Emitter cut-off current									
$V_{BE} = 3 V; I_C = 0$	I <sub>EBO</sub>	max.	50	nA					
Output capacitance at f = 100 kHz									
$I_E = 0; -V_{CB} = 5 V$	Cc	max.	4	pF					
Input capacitance at f = 100 kHz									
$I_C = 0; -V_{BE} = 0.5 V$	C <sub>e</sub>	max.	8	pF					
Saturation voltages									
$-I_C = 50 mA; -I_B = 5 mA$	-V <sub>CEsat</sub>	max.	0.3	V					
$-I_C = 50 mA; -I_B = 5 mA$	-VBEsat	max.	0.95	V					
D.C. current gain			100						
$-I_C = 2 mA; -V_{CE} = 1 V$	$h_{FE}$	min.	120						
	12	max.	360						
$-I_C = 50 \text{ mA}; -V_{CE} = 1 \text{ V}$	h <sub>FE</sub>	min.	60						
Noise figure at $R_S = 1$ kw	12								
$-I_C = 100 \text{ mA}; -V_{CE} = 5 V$									
f = 10  Hz to 15.7 kHz	NF	max.	6	dB					
Small signal current gain									
$V_{CE} = 1V; I_C = 2 mA; f = 1 KHz$	h <sub>fe</sub>	min.	120						
		max.	480						
Transition frequency									
$V_{CE} = 20V; I_C = 10 \text{ mA}; f = 100 \text{ MHz}$	$f_T$	min.	300	MHz					
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**Customer Notes** 

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Data Sheet